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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

1

of

2

Complete if Known

Application Number

Filing Date

First Named Inventor

Betti-Berutto, Andrea

Group Art Unit

2817

Examiner Name

Attorney Docket Number

021290-000100US

10/022012
12/14/01

U.S. PATENT DOCUMENTS

Examiner Initials *	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
JA	AA	4,598,256		Kinkel	Jul. 1, 1986	
JA	AB	4,495,429		Oda et al.	Jan. 22, 1985	
JA	AC	5,365,197		Ikalainen	Nov. 15, 1994	
JA	AD	5,550,513		Wong	Aug. 27, 1996	
JA	AE	5,880,640		Dueme	Mar. 9, 1999	
JA	AF	5,936,462		Muraishi	Aug. 10, 1999	
JA	AG	5,357,209		Mader et al.	Oct. 18, 1994	
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S J Mottola

Date
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12-26-02

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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Complete if Known	
		Application Number	
		Filing Date	
		First Named Inventor	Betti-Berutto, Andrea
		Group Art Unit	2817
		Examiner Name	
Sheet 2 of 2	Attorney Docket Number	021290-000100US	

OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
SP	AU	R. SCHMID ET AL., <i>40Gbit/s EAM driver IC in SiGe bipolar technology</i> , <u>Electronics Letters</u> 28th May 1998, Vol. 34, No. 11	
SP	AV	R. SCHMID ET AL., <i>SiGe Driver Circuit with High Output Amplitude Operating up to 23 Gb/s</i> , <u>IEEE Journal of Solid-State Circuits</u> , Vol. 34, No. 6, June 1999	
SP	AW	J. GODIN ET AL., <i>40 Gbit/s Optical Communications: InP DHBT technology, circuits and system experiments</i> , IEEE, 1999	
SP	AX	M. LEICH ET AL., <i>40 Gbit/s high voltage modulator driver in P-HEMT technology</i> , <u>Electronics Letters</u> , 14th October 1999, Vol. 35, No. 21	
SP	AY	Z. LAO ET AL., <i>DC 30 GHz bandwidth and 36 db gain limiting amplifier for 40 Gbit/s optical transmission systems</i> , <u>Electronics Letters</u> , 4th December 1997, Vol. 33, No. 25	
SP	AZ	ZHIHAO LAO ET AL., <i>40-Gb/s High-Power Modulator Driver IC for Lightwave Communication Systems</i> , <u>IEEE Journal of Solid-State Circuits</u> , Vol. 33, No. 10, October 1998	
SP	BA	J. GODIN ET AL., <i>Design of Decision and Driver Circuits for 40 Gbit/s Data Rate Optical Communication</i> , OPTO+, Groupement d'Intérêt Économique, Marcoussis, France (*France Telecom R&D) jean.godin@optoplus.fr	
SP	BB	MOUNIR MEGHELLI ET AL., <i>High Power and High Speed InP DHBT Driver IC's for Laser Modulation</i> , <u>IEEE Journal of Solid-State Circuits</u> , Vol.33, No. 9, September 1998	
SP	BC	A. THIAM ET AL., <i>40 Gbit/s GaAs P-HEMT driver module for optical communications</i> , <u>Electronics Letters</u> , 12th November 1998, Vol. 34, No. 23	

Examiner Signature	S J Mottola	Date Considered	12-26-02
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